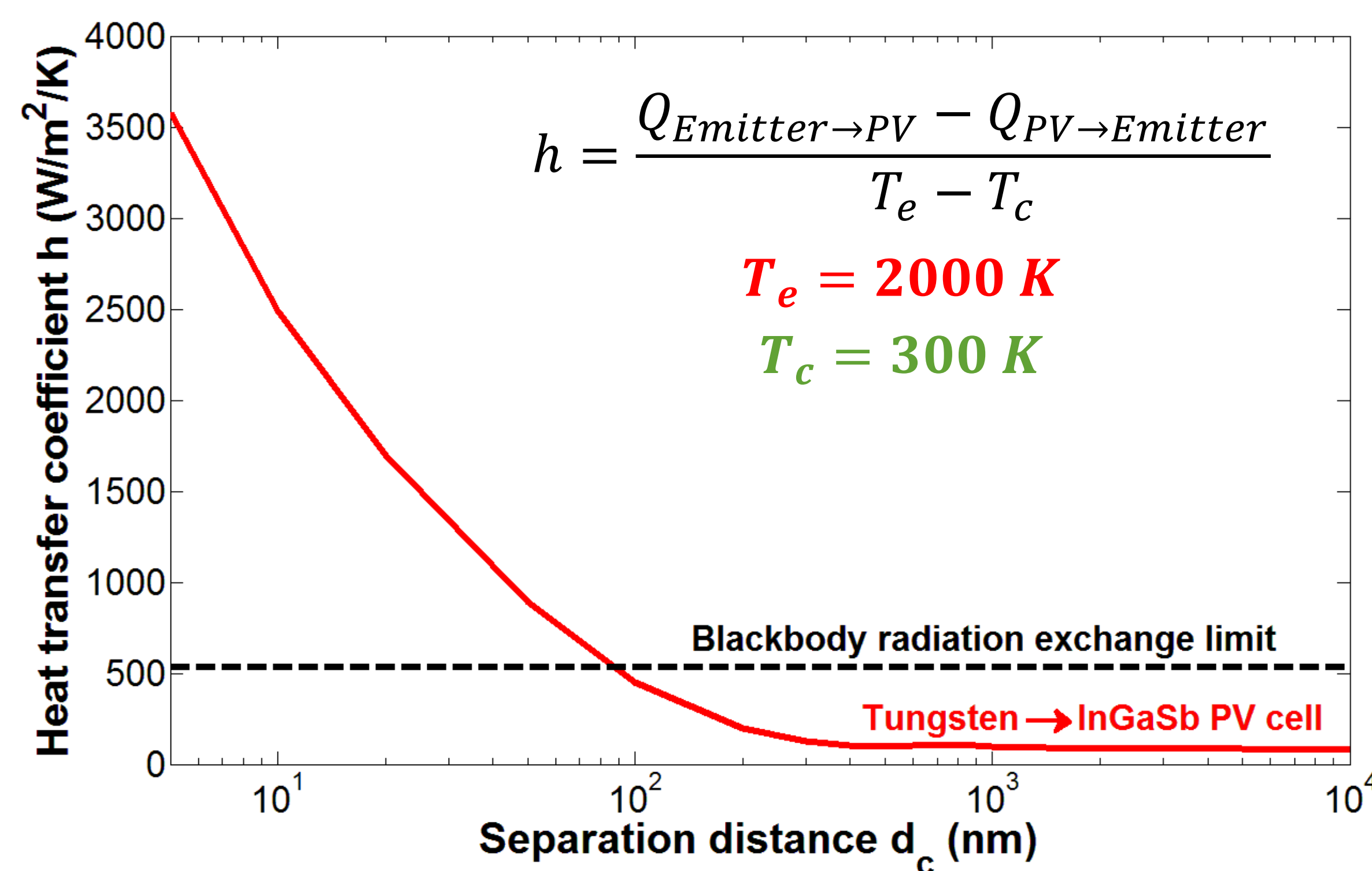


Modeling of Near-Field Concentrated Solar Thermophotovoltaic Microsystem

Introduction

- Solar Thermophotovoltaic cell (STPV) tailors solar spectrum to better match with PV cell quantum efficiency.
- Enhancement in radiation flux between two closely separated surface ($\sim \lambda_{radiation}$) can be orders of magnitudes higher than the **blackbody** limit, which can increase cell output power density.
- Flexible system; Solar energy.



Modeling

- Emitter/Absorber is made of Tungsten, selective absorber has a 2D Photonic crystal.
- PV cell is single PN junction ($In_{0.18}Ga_{0.82}Sb$) with bandgap $0.56 eV$.
- Near-field radiation is originated from source at \mathbf{z}' and calculated at PV cell at point \mathbf{z}

$$q(\mathbf{z}, \omega) = \frac{2k_v^2 \Theta(\omega, T)}{\pi} \text{Re} \left\{ i \epsilon_r''(\omega) \int_V dV' G_{m\alpha}^E(\mathbf{z}, \mathbf{z}', \omega) G_{n\alpha}^{H*}(\mathbf{z}, \mathbf{z}', \omega) \right\}$$

- Electron/hole generation rate in PV cell,

$$G(\mathbf{z}, \omega) = -\frac{1}{\hbar\omega} \frac{\partial q(\mathbf{z}, \omega)}{\partial z}$$

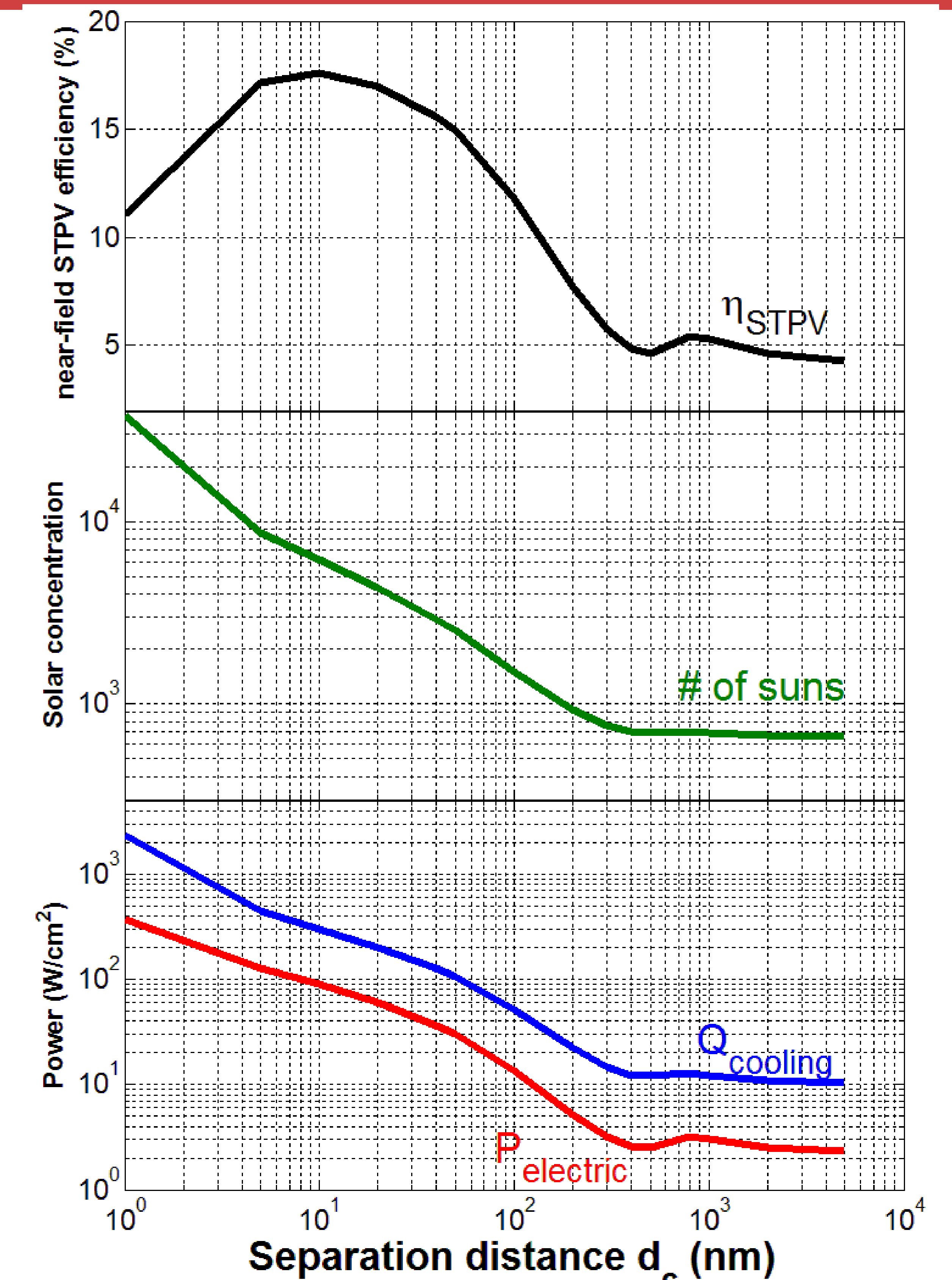
- Solving minority carrier diffusion equation, photocurrent is calculated,

$$D_{e,h} \frac{\partial^2 \Delta_{e,h}(\mathbf{z}, \omega)}{\partial z^2} + G(\mathbf{z}, \omega) - \frac{\Delta_{e,h}(\mathbf{z}, \omega)}{\tau_{e,h}} = 0$$

- Electron hole recombination is considered $\tau_{e,h}$ is lifetime of electron/hole.

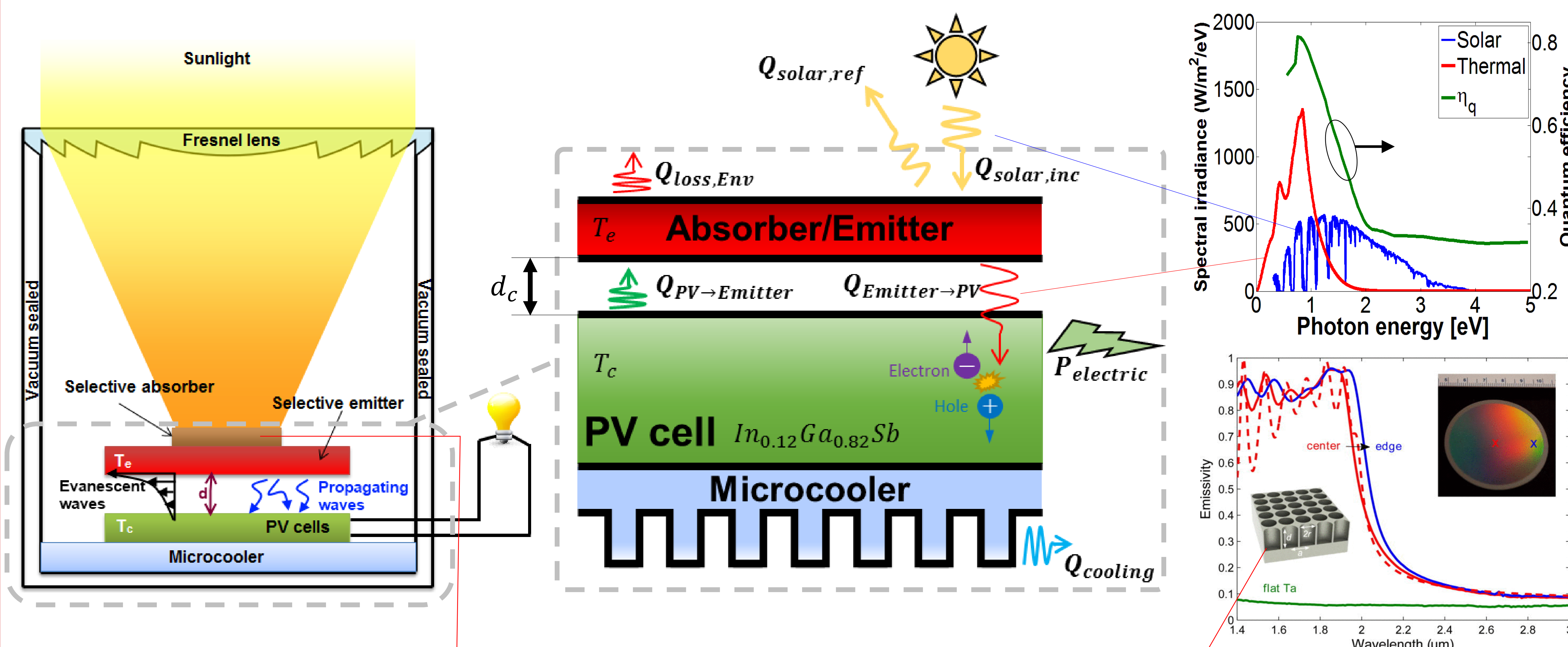
$$\eta_{STPV} = \frac{Q_{solar,inc}}{P_{electric}}$$

Results & conclusion



- Near-field STPV have potential for high power density ($100 W/cm^2$) compared to conventional PV cell ($0.845 W/cm^2$), with conversion efficiency 17.5%.
- Efficiency can be increased by employing special enclosure.
- Cooling may be a concern.

Model layout



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